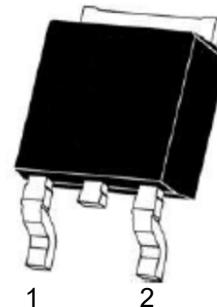


## Silicon Carbide Schottky Diode

### Feature

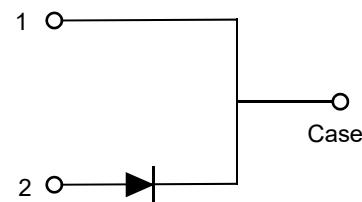
- 650-Volt Schottky Rectifier
- Optimized for PFC Boost Diode Application
- Zero Reverse Recovery Current
- Zero Forward Recovery Voltage
- High-Frequency Operation
- Temperature-Independent Switching Behavior
- Extremely Fast Switching
- Positive Temperature Coefficient on  $V_F$



**TO-252-2L**

### Applications

- Switch Mode Power Supplies (SMPS)
- Boost diodes in PFC or DC/DC stages
- Free Wheeling Diodes in Inverter stages
- AC/DC converters



**Circuit Diagram**

### Absolute maximum rating@25°C

Parameter	Symbol	Value	Units
Repetitive Peak Reverse Voltage	$V_{RRM}$	650	V
Surge Peak Reverse Voltage	$V_{RSM}$	650	V
DC Peak Reverse Voltage	$V_R$	650	V
Continuous Forward Current	$I_F$	14	A
		7.0	
		4.0	
Repetitive Peak Forward Surge Current	$I_{FRM}$	23	A
		15	
Non-repetitive Forward Surge Current	$I_{FSM}$	36	A
		28	
$i^2t$ Value	$\int i^2 dt$	6.5	$A^2s$
		3.9	
Power Dissipation	$P_{tot}$	51	W
		22	
Operating Junction Range	$T_J$	-55~+175	°C
Storage Temperature Range	$T_{STG}$	-55~+150	°C

# Silicon Carbide Schottky Diode

PSICS2DP650V4N

## Electrical characteristics per line@25°C (unless otherwise specified)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Units
Forward Voltage	$V_F$	$I_F = 4A, T_J=25^\circ C$	-	1.3	1.5	V
		$I_F = 4A, T_J=175^\circ C$	-	1.5	-	
Reverse Current	$I_R$	$V_R = 650V, T_J=25^\circ C$	-	10	50	$\mu A$
		$V_R = 650V, T_J=175^\circ C$	-	40	150	
Total Capacitive Charge	$Q_C$	$V_R = 400V$	-	10.6	-	nC
Total Capacitance	C	$V_R = 0V, f = 1MHz$	-	203	-	pF
		$V_R = 200V, f = 1MHz$	-	21	-	
		$V_R = 400V, f = 1MHz$	-	16	-	

## Thermal Characteristics

Parameter	Symbol	Min.	Typ.	Max.	Units
Thermal Resistance (Junction to case)	$R_{\theta JC}$	-	2.9	-	°C/W

## Typical Characteristics

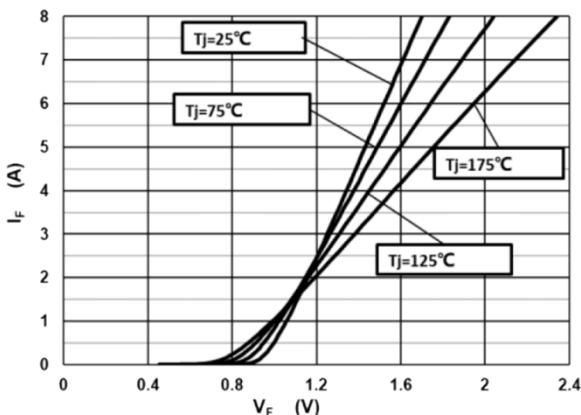


Fig.1 Forward Characteristics

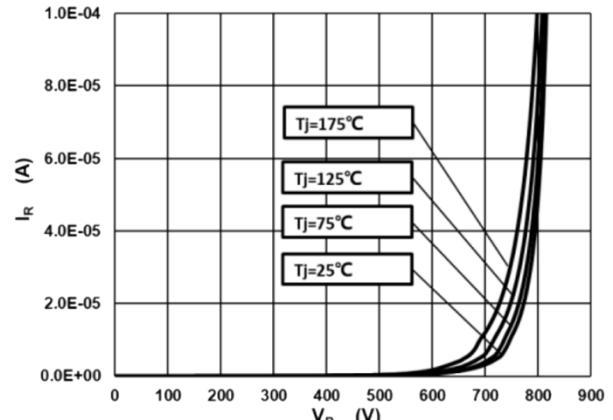


Fig.2 Reverse Characteristics

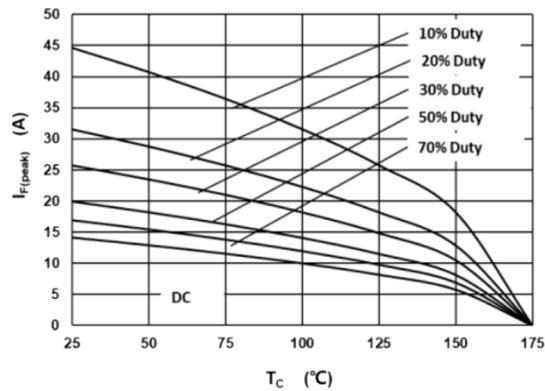


Fig.3 Current Derating

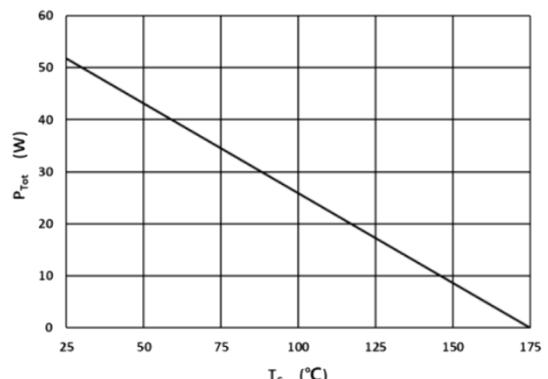


Fig.4 Power Derating

# Silicon Carbide Schottky Diode

PSICS2DP650V4N

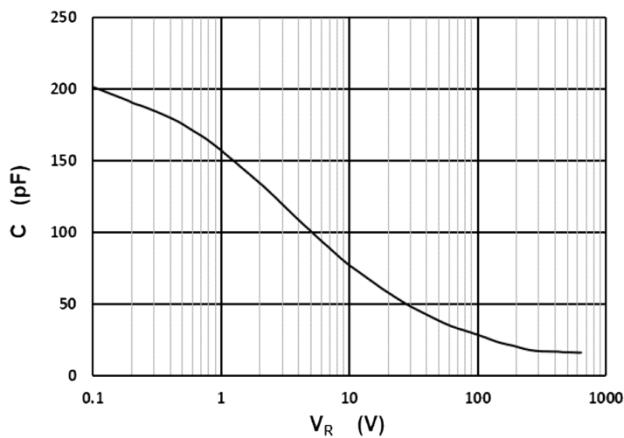


Fig.5 Capacitance vs. Reverse Voltage

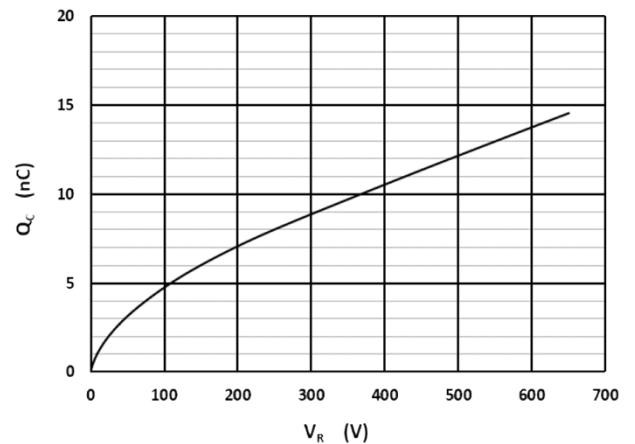


Fig.6 Capacitance Charge vs. Reverse Voltage

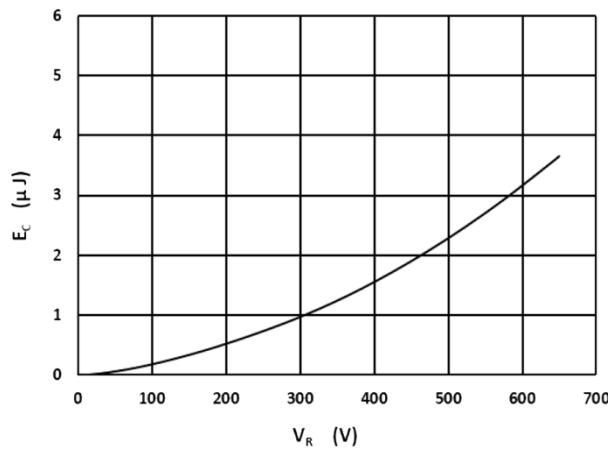


Fig.7 Capacitance Stored Energy

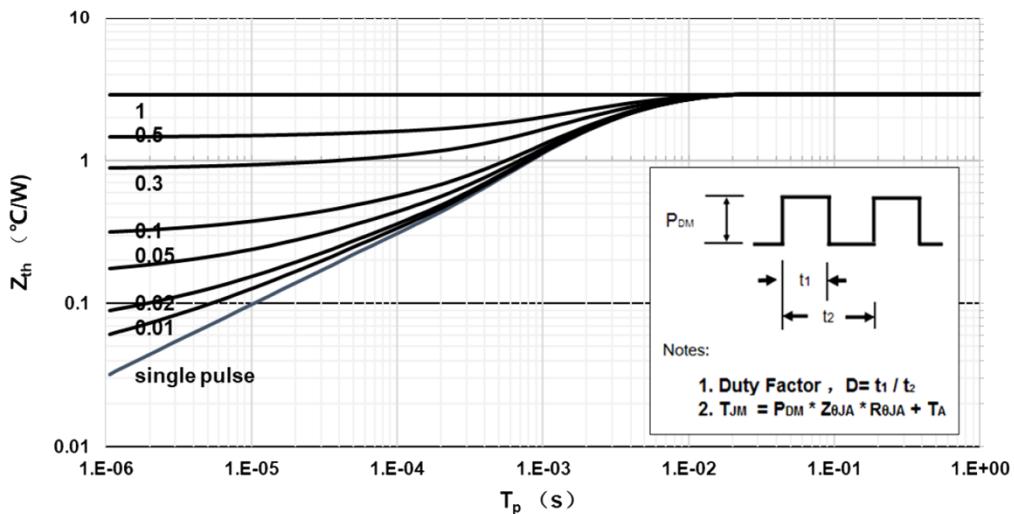
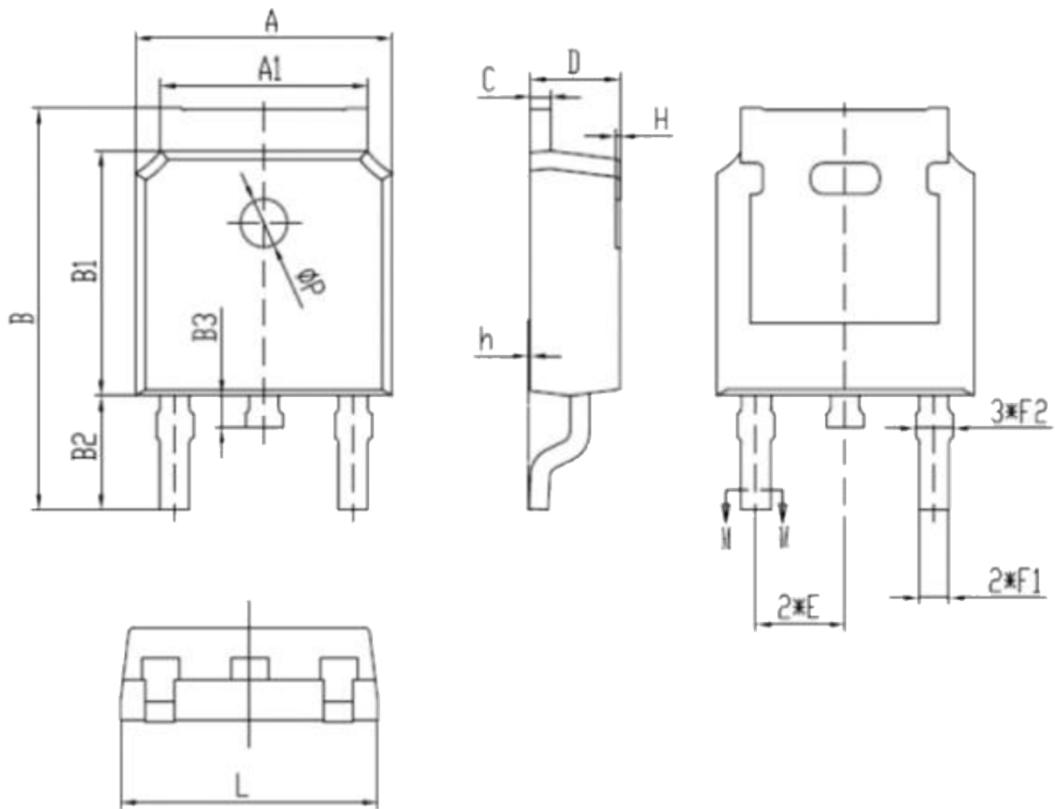


Fig.8 Transient Thermal Impedance

# Silicon Carbide Schottky Diode

PSICS2DP650V4N

## Product dimension (TO-252-2L)



Dim	Millimeters		Inches	
	Min	Max	Min	Max
A	6.50	6.70	0.256	0.264
A1	5.16	5.46	0.203	0.215
B	9.77	10.17	0.385	0.400
B1	6.00	6.20	0.236	0.244
B2	2.60	3.00	0.102	0.118
B3	0.70	0.90	0.028	0.035
C	0.45	0.61	0.018	0.024
D	2.20	2.40	0.087	0.094
E	2.186	2.386	0.086	0.094
F1	0.67	0.87	0.026	0.034
F2	0.76	0.96	0.030	0.038
H	0.00	0.30	0.000	0.012
h	0.00	0.127	0.000	0.005
L	6.50	6.70	0.256	0.264
φP	1.10	1.30	0.043	0.051

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